

6A Avg.

60 Volts

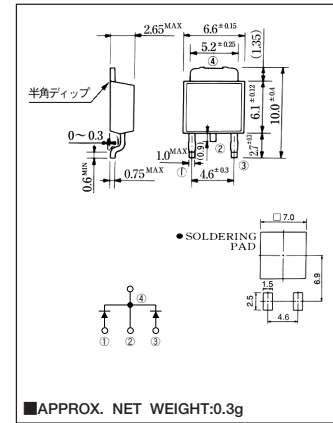
SBD

EA60QC06-F

■最大定格 Maximum Ratings

Item	Symbol	Conditions			Unit
くり返しピーク逆電圧 Repetitive Peak Reverse Voltage	V_{RRM}	60			V
非くり返しピーク逆電圧 Non-repetitive Peak Reverse Voltage	V_{RSM}	65			V
平均整流電流 Average Rectified Forward Current	I_O	50Hz、正弦全波通電抵抗負荷 50Hz Full Sine Wave Resistive Load	$T_a=27^\circ\text{C}$	1.5	A
			$T_c=104^\circ\text{C}$	6.0	A
実効順電流 R.M.S. Forward Current	$I_{F(RMS)}$	6.66			A
サージ順電流 Surge Forward Current	I_{FSM}	45 50Hz正弦全波、1サイクル、非くり返し 50Hz Full Sine Wave, 1cycle, Non-repetitive			A
動作接合温度範囲 Operating Junction Temperature Range	T_{jw}	-40~+150			$^\circ\text{C}$
保存温度範囲 Storage Temperature Range	T_{stg}	-40~+150			$^\circ\text{C}$

■OUTLINE DRAWING(mm)



■電氣的・熱的特性 Electrical/Thermal Characteristics

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
ピーク逆電流 Peak Reverse Current	I_{RM}	$T_j=25^\circ\text{C}$, $V_{RM}=V_{RRM}$, 一素子あたり Per Diode	—	—	3	mA
ピーク順電圧 Peak Forward Voltage	V_{FM}	$T_j=25^\circ\text{C}$, $I_{FM}=3\text{A}$, 一素子あたり Per Diode	—	—	0.58	V
熱抵抗 Thermal Resistance	$R_{th(j-a)}$	接合部・周囲間 Junction to Ambient	—	—	80	$^\circ\text{C/W}$
	$R_{th(j-c)}$	接合部・ケース間 Junction to Case	—	—	5	$^\circ\text{C/W}$

* Print Land = 20×20mm

■定格・特性曲線

